



# **General Description**

The MAX4885AE integrates high-bandwidth analog switches, level-translating buffers, and level-translating FET switches to implement a complete 2:1 multiplexer for VGA signals. The device provides three very highfrequency 900MHz (typ) SPDT switches for RGB signals, two low-frequency clamping switches for the DDC signals, a pair of level-translating buffers for the H\_ and V\_ signals, and integrated extended ESD protection.

Horizontal and vertical synchronization (H\_/V\_) inputs feature level-shifting buffers to support low-voltage controllers and standard 5V-TTL-compatible monitors, meeting the VESA requirement. Display Data Channel (DDC), consisting of SDA\_ and SCL\_, are FET switches that protect the low-voltage VGA source from potential damage from high-voltage presence on the monitor while reducing capacitive load.

All seven output terminals of the MAX4885AE feature high-ESD protection to ±15kV Human Body Model (HBM) (see the Pin Description). All other pins are protected to ±2kV Human Body Model (HBM).

The MAX4885AE is specified over the extended -40°C to +85°C temperature range, and is available in a spacesaving, 28-pin, 4mm x 4mm TQFN package.

# **Applications**

Notebook Computer—MXM/Switchable Graphics www.DataSheekVMPfor Servers

### **Features**

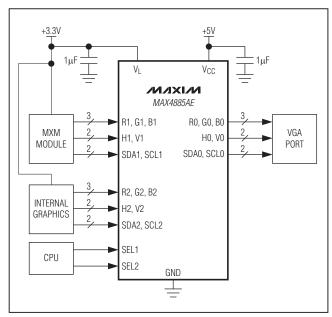
- ♦ Low 5Ω (typ) On-Resistance (R\_, G\_, B\_ Signals)
- ◆ Low 5.5pF (typ) On-Capacitance (R\_, G\_, B\_ Signals)
- ◆ Independent, Selectable Logic Inputs for **Switching**
- ♦ Similar Pin Configuration to MAX4885
- ◆ Ultra-Small, 28-Pin (4mm x 4mm) TQFN Package
- ♦ ±15kV ESD HBM

# **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE	
MAX4885AEETI+	-40°C to +85°C	28 TQFN-EP*	

<sup>+</sup>Denotes a lead(Pb)-free/RoHS-compliant package.

# **Typical Operating Circuit**



<sup>\*</sup>EP = Exposed pad.

# **MAX4885AE ABSOLUTE MAXIMUM RATINGS**

i	(All voltages referenced to GND unless otherwise noted.)
1	VCC0.3V to +6V
	VL0.3V to (VCC + 0.3V)
,	R_, G_, B_, H0, V0, SDA0, SCL00.3V to (VCC + 0.3V)
)	H1, H2, V1, V2, SDA1, SDA2, SCL1,
ı	SCL2, SEL1, SEL20.3V to (V <sub>L</sub> + 0.3V)
1	Continuous Current through R_, G_, B_ Switches ±50mA
	Continuous Current through SDA_, SCL_ Switches ±50mA
ı	Continuous Current into SEL1, SEL2, H1, H2, V1, V2 ±20mA
	Peak Current through all Switches
ı	(pulsed at 1ms, 10% duty cycle)±100mA

Continuous Power Dissipation (TA = +70°C	,
28-Pin TQFN (derate 28.6mW/°C above	+70°C)2285.7mW
Junction-to-Ambient Thermal Resistance (6	JA) (Note 1)
28-Pin TQFN	35°C/W
Junction-to-Ambient Thermal Resistance (6	JC) (Note 1)
28-Pin TQFN	3°C/W
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a fourlayer board. For detailed information on package thermal considerations, refer to http://www.maxim-ic.com/thermaltutorial.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = +4.5V \text{ to } +5.5V, V_L = +2.2V \text{ to } V_{CC}, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } T_A = +25^{\circ}C.)$ 

	PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
	Supply Voltage	Vcc		+4.5		+5.5	V
	Logic Supply Voltage	VL	V <sub>L</sub> ≤ V <sub>C</sub> C	+2.2		Vcc	V
	V <sub>CC</sub> Supply Current	Icc	V <sub>CC</sub> = +5.5V, V <sub>L</sub> = +3.6V, SEL_ = H1 = H2 = V1 = V2 = GND		2	5	μА
www.Da	ataSheet4U.com VL Supply Current	ΙL	$V_{CC} = +5.5V$ , $V_{L} = +3.6V$ , $SEL_{-} = H1 = H2 = V1 = V2 = GND$			1	μА
	ANALOG SWITCHES						
	On-Resistance (R_, G_, B_)	R-HF-ON	$V_{IN} = +0.7V$ , $I_{IN} = \pm 10mA$		5	8	Ω
	On-Resistance Match (R_, G_, B_)	ΔRon	0 ≤ VIN ≤ +0.7V, IIN = -10mA			1	Ω
	On-Resistance Flatness (R_, G_, B_)	RFLAT(ON)	$0 \le V_{IN} \le +0.7V$ , $I_{IN} = -10$ mA		0.5	1	Ω
	Off Leakage Current (R_, G_, B_)	loff	VR_, VG_, VB_ = 0V or VCC	-1		+1	μΑ
	On-Resistance (SDA_, SCL_)	R-DDCoN	$V_{IN} = +0.7V$ , $I_{IN} = \pm 10$ mA		15		Ω
	Off-Leakage Current (SDA_, SCL_)	IOFF	VSDA_, VSCL_ = 0V or VL, VCC = VL = +5V	-1		+1	μА

# **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = +4.5V \text{ to } +5.5V, V_L = +2.2V \text{ to } V_{CC}, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$  Typical values are at  $T_A = +25^{\circ}C.)$ 

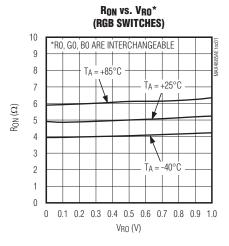
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DIGITAL INPUTS (SEL_, H1, H2,	V1, V2)					
Input Threshold Low	VIL		0.25 x VL			V
Input Threshold High	VIH				0.55 x V <sub>L</sub>	V
Input Hysteresis	VHYST			100		mV
Input Leakage Current	IL		-1		+1	μΑ
SEL_ Enable/Disable Time	ton, toff	R <sub>L</sub> = $2.2k\Omega$ , C <sub>L</sub> = $10pF$ , Figure 1		300		ns
DIGITAL OUTPUTS (H0, V0)						
Output-Voltage Low	VOL	$I_{OUT} = 8mA$ , $V_{CC} = +4.5V$			0.8	V
Output-Voltage High	Voн	$I_{OUT} = -8mA$ , $V_{CC} = +4.5V$	2.4			V
Rise/Fall Time	t <sub>R</sub> , t <sub>F</sub>	R <sub>L</sub> = $2.2k\Omega$ , C <sub>L</sub> = $10pF$ , Figure 2			8	ns
RGB AC PERFORMANCE						
Bandwidth	fMAX	$R_S = R_L = 50\Omega$		900		MHz
On-Loss	ILOSS	$\label{eq:free_state} \left  \begin{array}{l} f = 10 \text{MHz},  \text{Rs} = \text{R}_L = 50 \Omega,  0 \leq \text{V} \leq +0.7 \text{V}, \\ \text{Figure 3} \end{array} \right $		0.4		dB
Crosstalk R_, G_, B_	VCT	$f = 50MHz$ , $R_S = R_L = 50\Omega$ , Figure 3		-40		dB
Off-Capacitance	Coff	f = 1MHz, R0 to R1/R2, G0 to G1/G2, B0 to B1/B2 (Note 2)		2.5		pF
On-Capacitance	Con	f = 1MHz, R0 to R1/R2, G0 to G1/G2, B0 to B1/B2 (Note 2)		5.5	8	pF
ESD PROTECTION			•			
R0, G0, B0, SDA0, SCL0, H0, V0	VESD	HBM (Notes 2, 3)		±15		kV
R0, G0, B0, SDA0, SCL0, H0, V0	VESD	IEC 61000-4-2 Contact (Notes 2, 3)		±8		kV
All Other Terminals	VESD	HBM (Note 2)		±2		kV

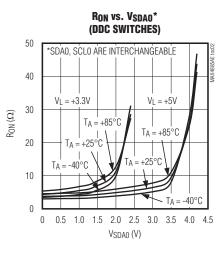
Note 2: Guaranteed by design. Not production tested.

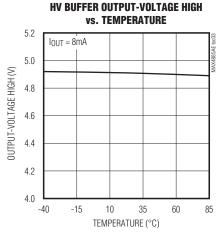
Note 3: Tested terminal to GND, 1 $\mu F$  bypass capacitors on V<sub>CC</sub> and V<sub>L</sub>.

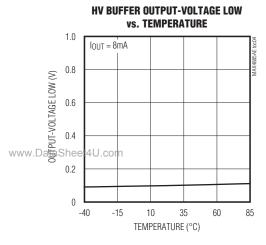
# **Typical Operating Characteristics**

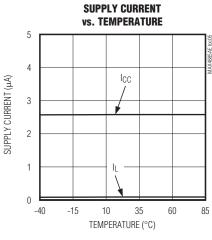
 $(V_{CC} = +5.0V, V_{L} = +3.3V, T_{A} = 25^{\circ}C, unless otherwise noted.)$ 

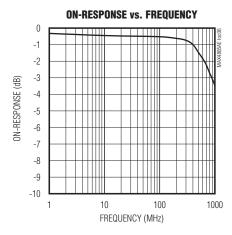


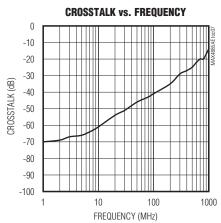




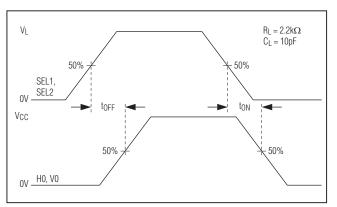








# Test Circuits/Timing Diagrams



VCC  $\frac{80\%}{V}$   $\frac{R_L = 2.2k\Omega}{C_L = 10pF}$   $\frac{80\%}{V}$   $\frac{R_L = 2.2k\Omega}{C_L = 10pF}$ 

Figure 1. Enable/Disable Time

Figure 2. Rise/Fall Time

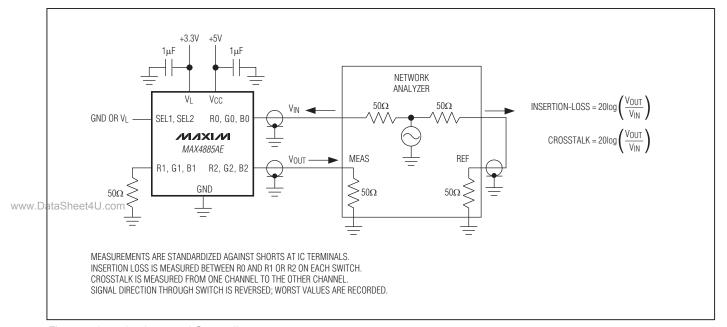
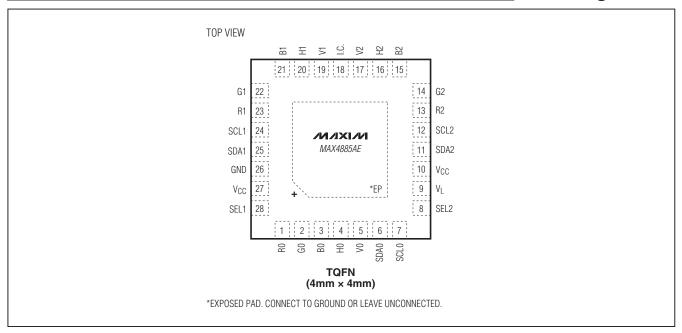


Figure 3. Insertion Loss and Crosstalk

# **Pin Configuration**



# **Pin Description**

	PIN	NAME	FUNCTION
	1	R0	RGB Red Output (Note 4)
	2	G0	RGB Green Output (Note 4)
www.Da	ataSgeet4	U.980	RGB Blue Output (Note 4)
	4	H0	Horizontal Sync Output (Note 4)
	5	V0	Vertical Sync Output (Note 4)
	6	SDA0	I <sup>2</sup> C Data Output (Note 4)
	7	SCL0	I <sup>2</sup> C Clock Output (Note 4)
	8	SEL2	Select Input 2. Switches SDA_ and SCL_ signals.
	9	VL	Supply Voltage. +2.2V ≤ V <sub>L</sub> ≤ V <sub>CC</sub> . Bypass V <sub>L</sub> to GND with a 1µF or larger ceramic capacitor.
	10	Vcc	Supply Voltage. VCC = +5.0V ±10%. Bypass VCC to GND with a 1μF or larger ceramic capacitor.
	11	SDA2	I <sup>2</sup> C Input Data 2 (Note 5)
	12	SCL2	I <sup>2</sup> C Input Clock 2 (Note 5)
	13	R2	RGB Red Input 2 (Note 6)
	14	G2	RGB Green Input 2 (Note 6)
	15	B2	RGB-Blue Input 2 (Note 6)
	16	H2	Horizontal Sync Input 2 (Note 7)
	17	V2	Vertical Sync Input 2 (Note 7)
	18	I.C.	Internal Connection. Connect to ground or leave unconnected.
	19	V1	Vertical Sync Input 1 (Note 7)
	20	H1	Horizontal Sync Input 1 (Note 7)
	21	B1	RGB Blue Input 1 (Note 6)

# Pin Description (continued)

PIN	NAME	FUNCTION
22	G1	RGB Green Input 1 (Note 6)
23	R1	RGB Red Input 1 (Note 6)
24	SCL1	I <sup>2</sup> C Clock Input 1 (Note 5)
25	SDA1	I <sup>2</sup> C Data Input 1 (Note 5)
26	GND	Ground
27	Vcc	+5V Supply Pin
28	SEL1	Select Input 1. Switches R_, G_, B_, H_, and V_ signals.
_	EP	Exposed Pad. Connect exposed pad to ground or leave unconnected.

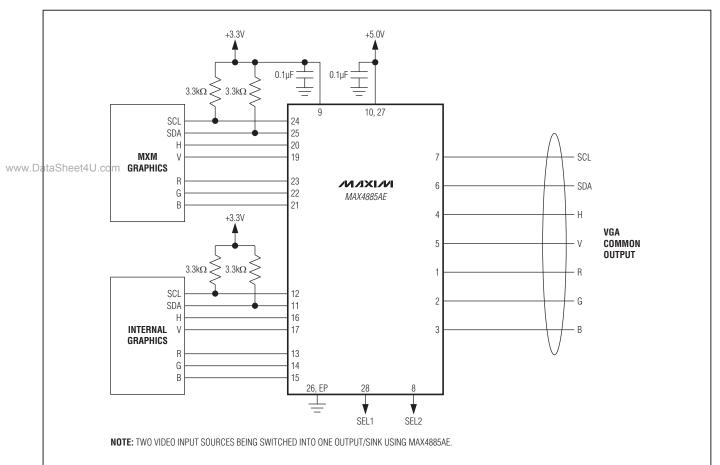
Note 4: Terminal with ±15kV HBM protection.

Note 5: SCL1, SCL2, SDA1, and SDA2 are identical and can be used interchangeably.

Note 6: R1, R2, G1, G2, B1, and B2 are identical and can be used interchangeably.

Note 7: H1, H2, V1, and V2 are identical and can be used interchangeably.

# **Typical Applications Circuit**



# **MAX4885AE Functional Diagram** - R0 G0 - B0 B2 -SCL0 SCL1 -SCL2 -SDA1 -- SDA0 SDA2 -MIXIM MAX4885AE www.DataSheet4U.com SEL1 -CONTROL SEL2

# **Detailed Description**

The MAX4885AE integrates high-bandwidth analog switches and level-translating buffers to implement a complete 2:1 multiplexer for VGA signals. The device provides switching for RGB, HSYNC, VSYNC, SDA, and SCL signals. These signals are required in notebook VGA switching applications.

The HSYNC and VSYNC inputs feature level-shifting buffers to support 5V-TTL output logic levels from low-voltage graphics controllers. These buffered switches can be driven from +2.0V up to +5.5V. RGB signals are routed with high-performance analog switches. SDA\_ and SCL\_ are I<sup>2</sup>C signals with pullups to their respective voltages. The MAX4885AE protects the low-voltage side while effectively translating up to the high-voltage level.

Two select inputs are provided to individually select groups of switches.

RGB, HSYNC, and VSYNC signals are controlled by SEL1; and both SDA\_ and SCL\_ signals are controlled by SEL2.

Table 1. RGB/HV Truth Table

	SEL1	FUNC	TION
	0	R1 to R0 G1 to G0 B1 to B0	H1 to H0 V1 to V0
www.Da	ataSheet4	R2 to R0 \$2% G0 B2 to B0	H2 to H0 V2 to V0

### **Table 2. DDC Truth Table**

SEL2	FUNCTION		
0	SDA1 to SDA0 SCL1 to SCL0		
1	SDA2 to SDA0 SCL2 to SCL0		

### **RGB Switches**

The MAX4885AE provides three SPDT high-bandwidth switches to route standard VGA  $R_{-}$ ,  $G_{-}$ , and  $B_{-}$  signals (see Table 1). The  $R_{-}$ ,  $G_{-}$ , and  $B_{-}$  analog switches are identical and any of the three switches can be used to route red, green, or blue video signals. The R0, G0, and B0 outputs are ESD protected to  $\pm 15 kV$  (HBM).

### Horizontal/Vertical Sync Level Shifter

H1, H2, V1, and V2 inputs are buffered to provide level-shifting and drive capability for horizontal/vertical sync signals that meet the VESA specification. The H $_$  and V $_$  level-shifters are identical, and each level-shifter can be used for either horizontal or vertical signals. The SDA0 and SCL0 outputs are ESD protected to  $\pm 15 \text{kV}$  (HBM).

### **Display-Data Channel Multiplexer**

The MAX4885AE provides two logic-level translating switches to route DDC signals (see Table 2).  $V_L$  is normally set to  $\pm 3.3V$  to provide logic-shifting for VESA I2C-compatible signals. The MAX4885AE protects the low-voltage graphics controller from  $\pm 5V$  that could be present in VESA-compatible monitors. In some applications, such as KVM, where logic-level shifting is not required, then  $V_L$  can be connected to  $V_C$ . The SDA\_ and SCL\_ switches are identical, and each switch can be used to route either SDA\_ or SCL\_ signals. The SDA0 and SCL0 outputs are ESD protected to  $\pm 15kV$  (HBM).

### **ESD Protection**

As with all Maxim devices, ESD-protection structures are incorporated on all pins to protect against electrostatic discharges encountered during handling and assembly. Additionally, the R0, G0, B0, H0, V0, SDA0, and SCL0 terminals of the MAX4885AE are designed for protection to the following limit: ±15kV using the HBM.

For optimum ESD performance, bypass  $V_{CC}$  and  $V_L$  pins to ground with  $1\mu F$  or larger ceramic capacitors as close as possible to these supply pins.

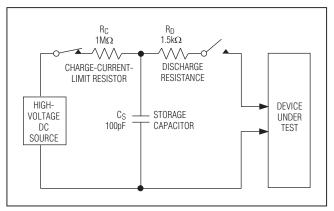


Figure 4. Human Body ESD Test Model

# AMPERES 36.8% 10% 1 TIME CURRENT WAVEFORM

Figure 5. Human Body Model Current Waveform

### **Human Body Model**

Figure 4 shows the HBM, and Figure 5 shows the current waveform it generates when discharged into a low-impedance state. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the device through a  $1.5 \mathrm{k}\Omega$  resistor.

### **ESD Test Conditions**

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report, test setup, methodology, and results.

# **Applications Information**

The MAX4885AE provides the switching and level-www.DataSheet4U.com shifting necessary to drive a standard VGA port from either an internal graphics controller or an add-in module (MXM or GPU—see *Typical Applications Circuit*). The R\_, G\_, and B\_ signals are switched through the three low-capacitance SPDT switches. Internal buffers drive the HSYNC and VSYNC signals to VGA standard 5V-TTL levels. The DDC multiplexer provides level-shifting. Connect VL to +3.3V for normal operation, or to VCC to disable level-shifting for DDC signals as for KVM application.

## **Power-Supply Decoupling**

Bypass each VCC pin and  $V_L$  pin to ground with a 1 $\mu$ F or larger ceramic capacitor as close as possible to the device.

# **PCB** Layout

High-speed switches such as the MAX4885AE requires proper PCB layout for optimum performance. Ensure that impedance-controlled PCB traces for high-speed signals are matched in length and as short as possible. Connect the exposed pad to ground or leave unconnected.

# **Chip Information**

PROCESS: BICMOS

# Package Information

For the latest package outline information and land patterns, go to <a href="www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.	
28 TQFN-EP	T2844+1	<u>21-0139</u>	

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